



L6221A L6221AD L6221N

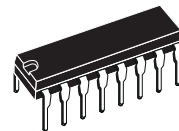
QUAD DARLINGTON SWITCH

- FOUR NON INVERTING INPUTS WITH ENABLE
- OUTPUT VOLTAGE UP TO 50 V
- OUTPUT CURRENT UP TO 1.8 A
- VERY LOW SATURATION VOLTAGE
- TTL COMPATIBLE INPUTS
- INTEGRAL FAST RECIRCULATION DIODES

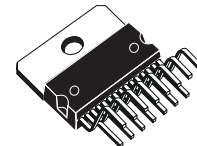
DESCRIPTION

The L6221 monolithic quad darlington switch is designed for high current, high voltage switching applications. Each of the four switches is controlled by a logic input and all four are controlled by a common enable input. All inputs are TTL-compatible for direct connection to logic circuits.

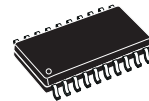
Each switch consists of an open-collector darlington transistor plus a fast diode for switching applications with inductive device loads. The emitters of the four switches are commoned. Any number of inputs and outputs of the same device may be paralleled.



Powerdip 12 + 2 + 2



Multiwatt 15

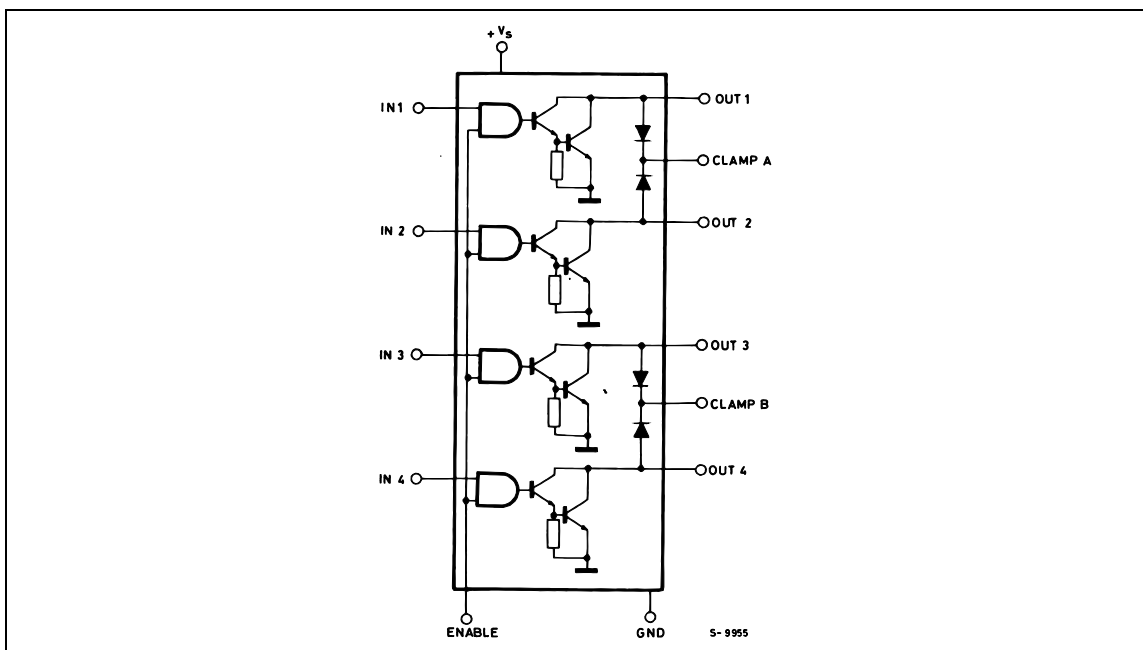


SO16+2+2

ORDERING NUMBERS:

L6221A (Powerdip)
L6221N (Multiwatt15)
L6221AD (SO16+2+2)

BLOCK DIAGRAM

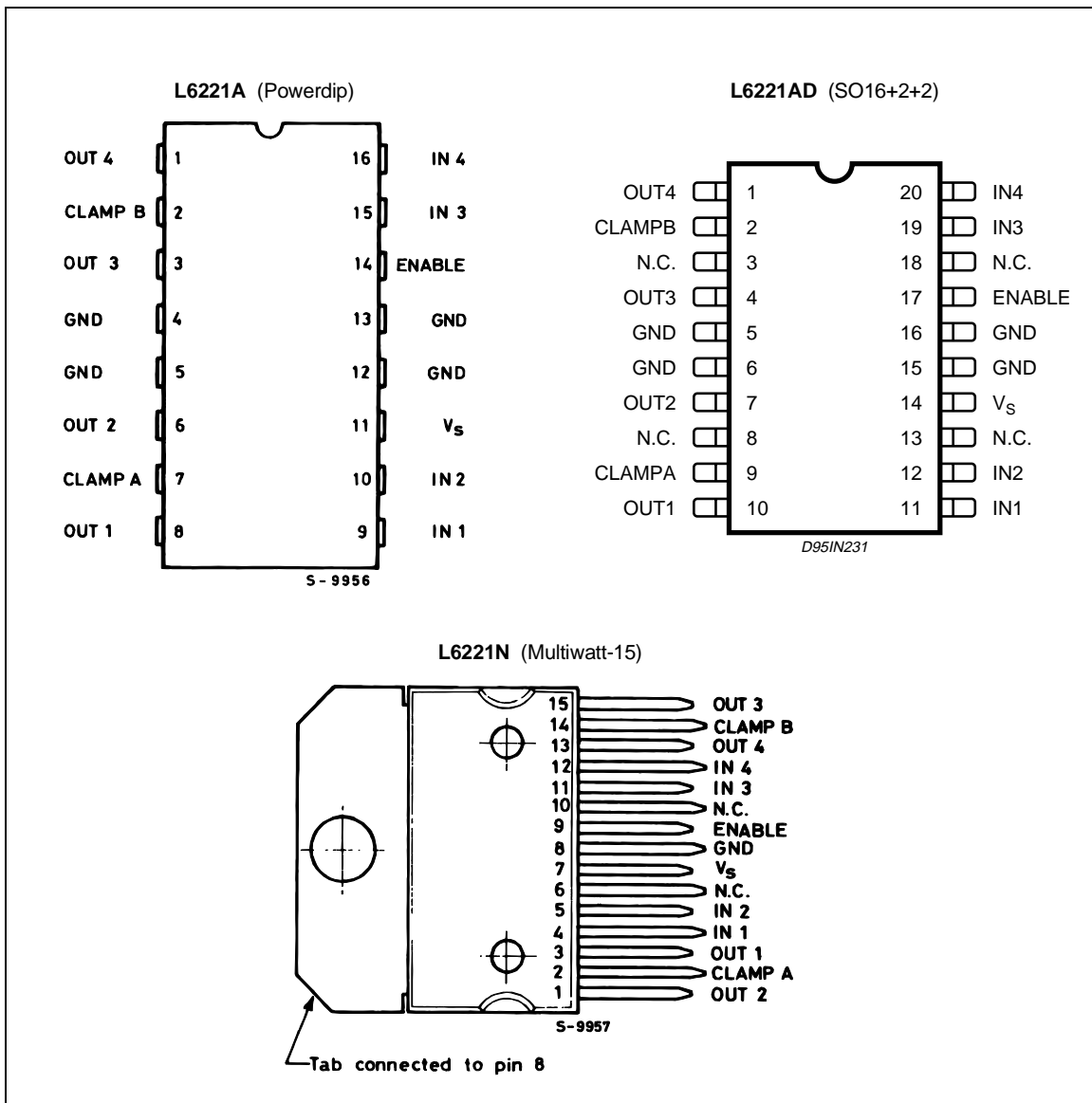


L6221A - L6221AD - L6221N

THERMAL DATA

Symbol	Parameter		SO20	Powerdip	Multiwatt15	Unit
$R_{th\ j-pins}$	Thermal Resistance Junction-pins	Max.	17	14	—	°C/W
$R_{th\ j-case}$	Thermal Resistance Junction-case	Max.	—	—	3	°C/W
$R_{th\ j-amb}$	Thermal Resistance Junction-ambient	Max.	80	80	35	°C/W

PIN CONNECTIONS (top views)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_o	Output Voltage	50	V
V_s	Logic Supply Voltage	7	V
V_{IN}, V_{EN}	Input Voltage, Enable Voltage	V_s	
I_C	Continuous Collector Current (for each channel)	1.8	A
I_C	Collector Peak Current (repetitive, duty cycle = 10 % $t_{on} = 5$ ms)	2.5	A
I_C	Collector Peak Current (non repetitive, $t = 10$ μ s)	3.2	A
T_{op}	Operating Temperature Range (junction)	- 40 to + 150	$^{\circ}$ C
T_{stg}	Storage Temperature Range	- 55 to + 150	$^{\circ}$ C
I_{sub}	Output Substrate Current	350	mA
P_{tot}	Total Power Dissipation		
	at $T_{pins} = 90$ $^{\circ}$ C (powerdip)	4.3	W
	at $T_{case} = 90$ $^{\circ}$ C (multiwatt)	20	W
	at $T_{case} = 90$ $^{\circ}$ C (SO20)	3.5	W
	at $T_{amb} = 70$ $^{\circ}$ C (powerdip)	1	W
	at $T_{amb} = 70$ $^{\circ}$ C (multiwatt)	2.3	W
	at $T_{amb} = 70$ $^{\circ}$ C (SO20)	1	W

TRUTH TABLE

Enable	Input	Power Out
H	H	ON
H	L	OFF
L	X	OFF

For each input : H = High level
L = Low level

PIN FUNCTIONS (see block diagram)

Name	Function
IN 1	Input to Driver 1
IN 2	Input to Driver 2
OUT 1	Output of Driver 1
OUT 2	Output of Driver 2
CLAMP A	Diode Clamp to Driver 1 and Driver 2
IN 3	Input to Driver 3
IN 4	Input to Driver 4
OUT 3	Output of Driver 3
OUT 4	Output of Driver 4
CLAMP B	Diode Clamp to Driver 3 and Driver 4
ENABLE	Enable Input to All Drivers
V_s	Logic Supply Voltage
GND	Common Ground

L6221A - L6221AD - L6221N

ELECTRICAL CHARACTERISTICS

Refer to the test circuit to Fig. 1 to Fig. 9 ($V_S = 5V$, $T_{amb} = 25^\circ C$ unless otherwise specified)

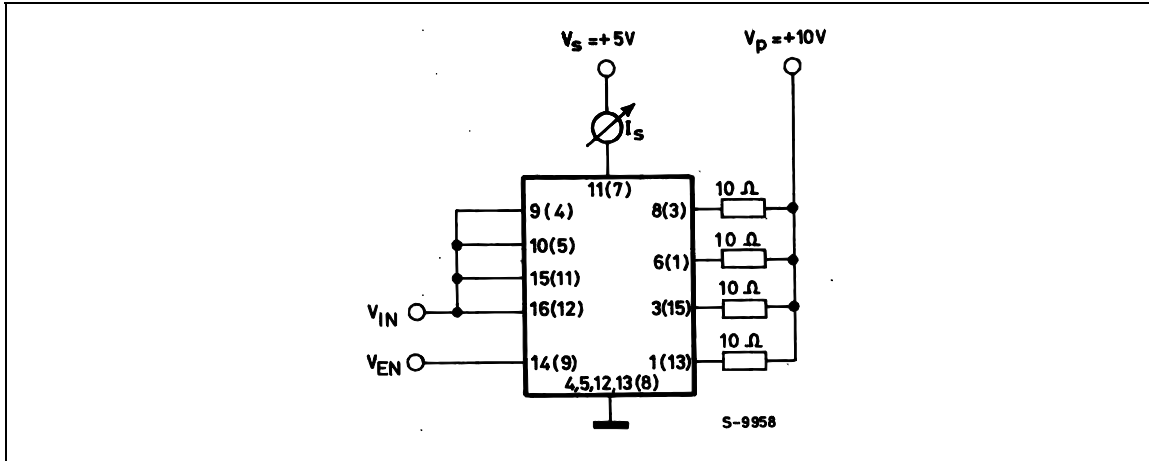
Symbol	Parameter	Test Conditions	Min .	Typ .	Max .	Unit
V_S	Logic Supply Voltage		4.5		5.5	V
I_S	Logic Supply Current	All Outputs ON, $I_C = 0.7A$ All Outputs OFF			20 20	mA mA
$V_{CE(sus)}$	Output Sustaining Voltage	$V_{IN} = V_{INL}$, $V_{EN} = V_{ENH}$ $I_C = 100\text{ mA}$	46			V
I_{CEX}	Output Leakage Current	$V_{CE} = 50V$ $V_{IN} = V_{INL}$, $V_{EN} = V_{ENH}$			1	mA
$V_{CE(sat)}$	Collector Emitter Saturation Voltage (one input on ; all others inputs off.)	$V_S = 4.5V$ $V_{IN} = V_{INH}$, $V_{EN} = V_{ENH}$ $I_C = 0.6A$ $I_C = 1A$ $I_C = 1.8A$			1 1.2 1.6	V
V_{INL} , V_{ENL}	Input Low Voltage				0.8	V
I_{INL} , I_{ENL}	Input Low Current	$V_{IN} = V_{INL}$, $V_{EN} = V_{ENL}$			- 100	μA
V_{INH} , V_{ENH}	Input High Voltage		2.0			V
I_{INH} , I_{ENH}	Input High Current	$V_{IN} = V_{INH}$, $V_{EN} = V_{ENH}$			± 10	μA
I_R	Clamp Diode Leakage Current	$V_R = 50\text{ V}$, $V_{EN} = V_{ENH}$ $V_{IN} = V_{INL}$			100	μA
V_F	Clamp Diode Forward Voltage	$I_F = 1A$ $I_F = 1.8A$			1.6 2.0	V V
$t_d(\text{on})$	Turn on Delay Time	$V_P = 5V$, $R_L = 10\Omega$			2	μs
$t_d(\text{off})$	Turn off Delay Time	$V_P = 5V$, $R_L = 10\Omega$			5	μs
ΔI_S	Logic Supply Current Variation	$V_{IN} = 5V$, $V_{EN} = 5V$ $I_{out} = - 300\text{ mA}$ for Each Channel			120	mA

TEST CIRCUITS

(X) = Referred to Multiwatt package

X = Referred to Powerdip package

Figure 1 : Logic supply current.



Set $V_{IN} = 4.5V$, $V_{EN} = 0.8V$, or $V_{IN} = 0.8V$, $V_{EN} = 4.5V$, for I_S (all outputs off)

Set $V_{IN} = 2V$, $V_{EN} = 2V$, for I_S (all outputs on)

Figure 2 : Output Sustaining Voltage.

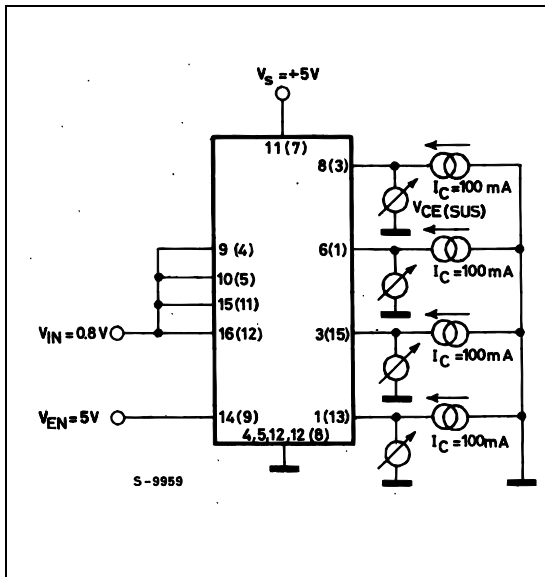


Figure 3 : Output Leakage Current.

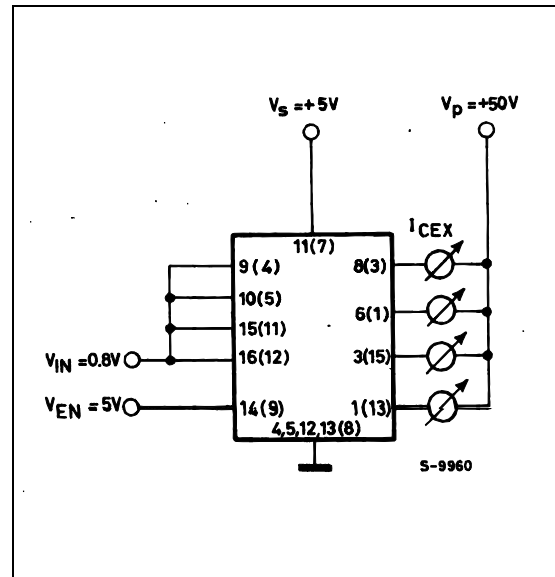


Figure 4 : Collector-emitter Saturation Voltage

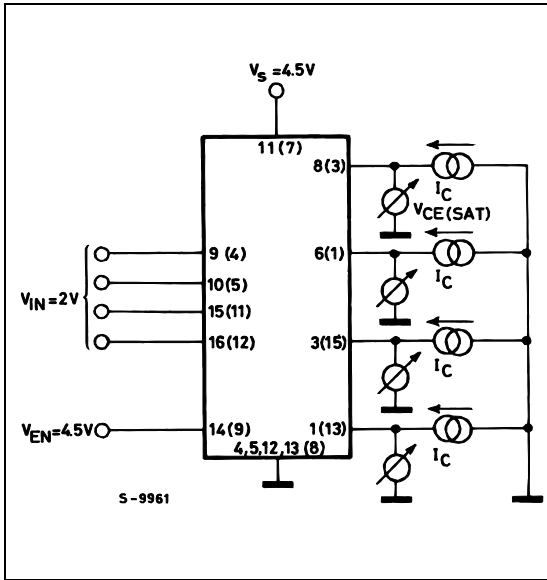
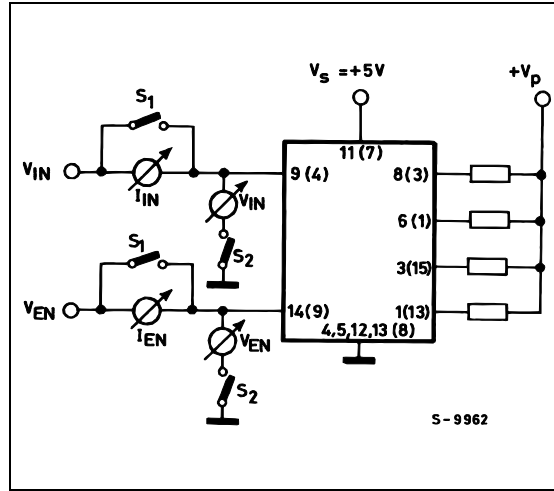


Figure 5 : Logic Input Characteristics



Set S₁, S₂ open, V_{IN}, V_{EN} = 0.8V for I_{IN} L, I_{EN} L
 Set S₁, S₂ open, V_{IN}, V_{EN} = 2V for I_{IN} H, I_{EN} H
 Set S₁, S₂ close, V_{IN}, V_{EN} = 0.8V for V_{IN} L, V_{EN} L
 Set S₁, S₂ close, V_{IN}, V_{EN} = 2V for V_{IN} H, V_{EN} H

Figure 6 : Clamp Diode Leakage Current.

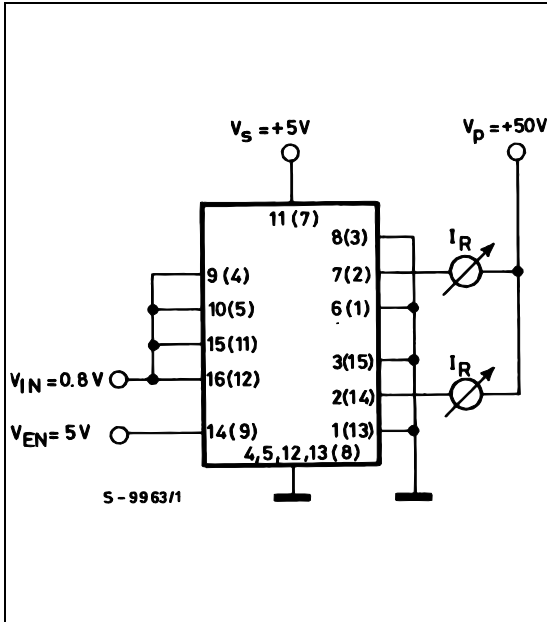


Figure 7 : Clamp Diode Forward Voltage.

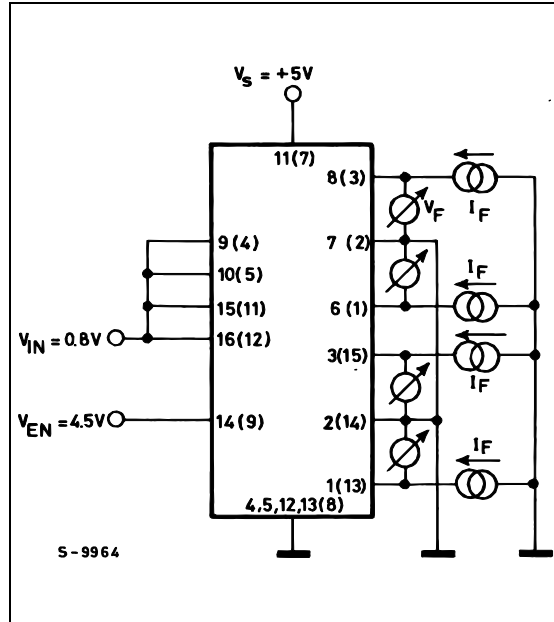


Figure 8 : Switching Times Test Circuit.

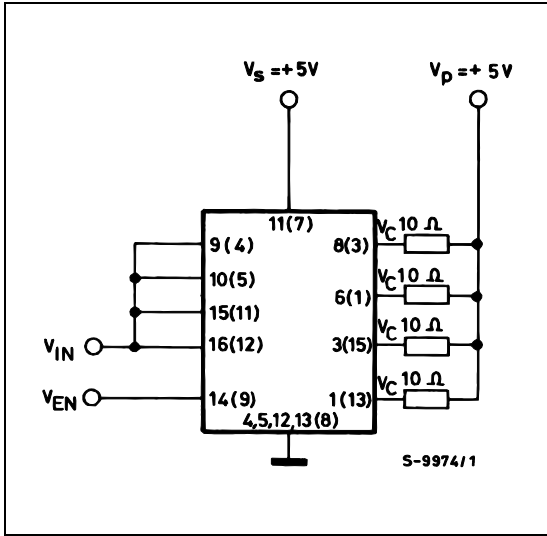


Figure 9 : Switching Times Waveforms.

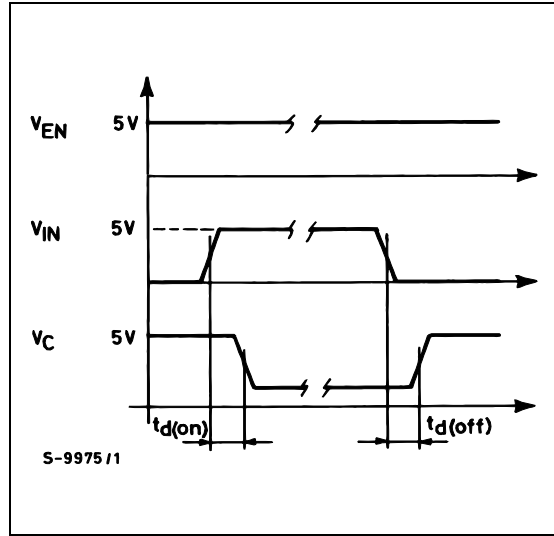


Figure 10 : Allowed Peak Collector Current versus Duty Cycle for 1, 2, 3 or 4 Contemporary Working Outputs (L6221A)

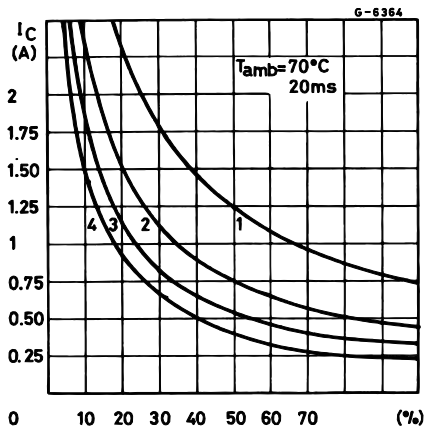


Figure 11 : Allowed Peak Collector Current versus Duty Cycle for 1, 2, 3 or 4 Contemporary Working Outputs (L6221N)

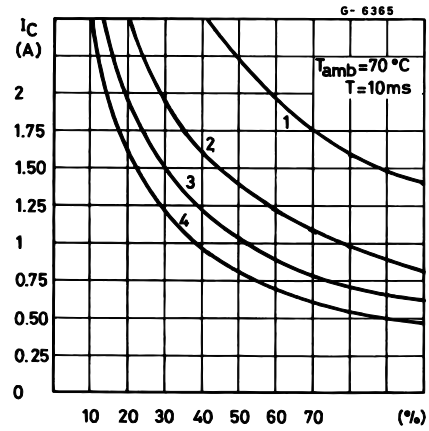


Figure 12 : Collector Saturation Voltage versus Collector Current

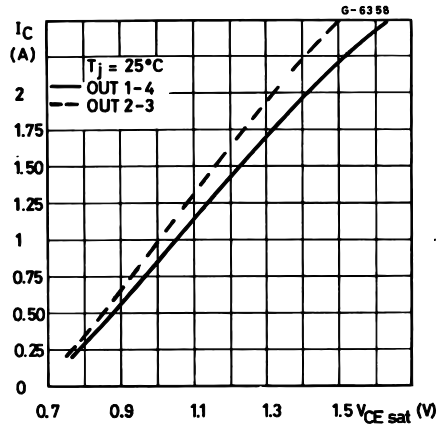


Figure 13 : Free-wheeling Diode Forward Voltage versus Diode Current

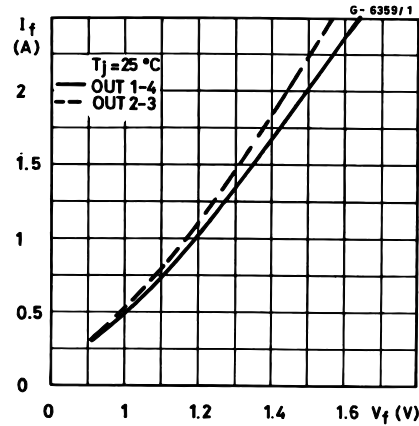


Figure 14 : Collector Saturation Voltage versus Junction Temperature at IC = 1A

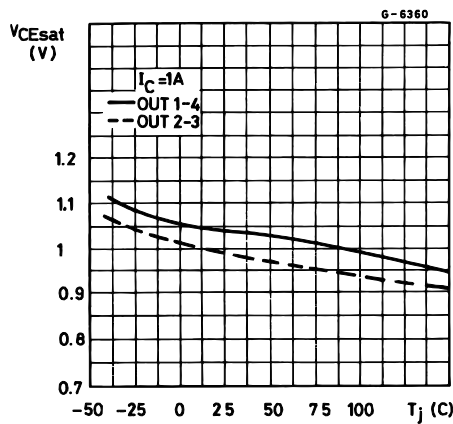


Figure 15 : Free-wheeling Diode Forward Voltage versus Junction Temperature at IF = 1A

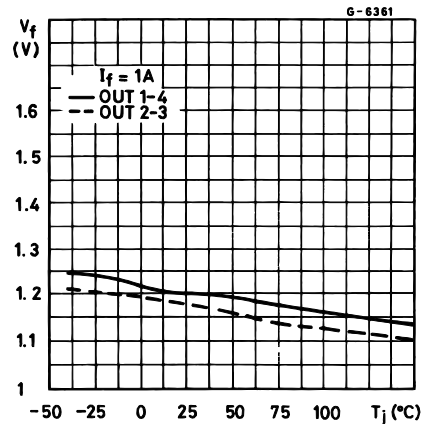


Figure 16 : Saturation Voltage vs. Junc-

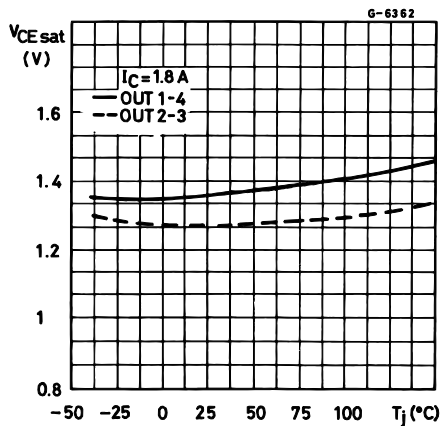
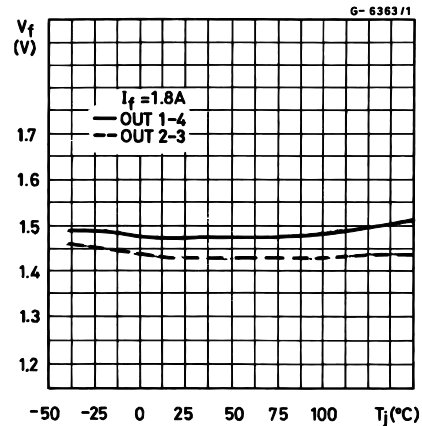


Figure 17 : Free-wheeling Diode Forward



APPLICATION INFORMATION

When inductive loads are driven by L6221A/N, a zener diode in series with the integral free-wheeling diodes increases the voltage across which energy stored in the load is discharged and therefore speeds the current decay (fig. 18).

For reliability it is suggested that the zener is chosen so that $V_p + V_z < 35\text{ V}$.

The reasons for this are two fold :

- 1) The zener voltage changes in temperature and current.
- 2) The instantaneous power must be limited to avoid the reverse second breakdown.

Figure 18.

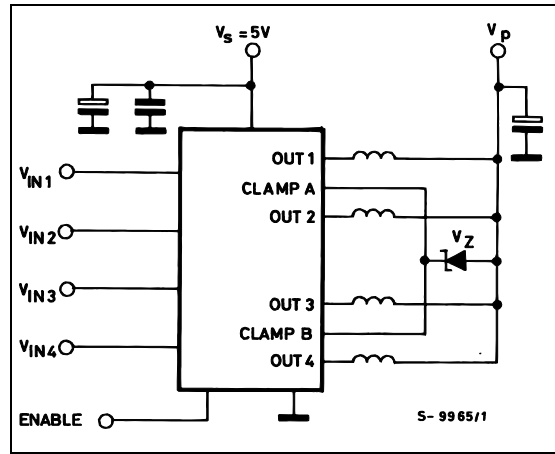
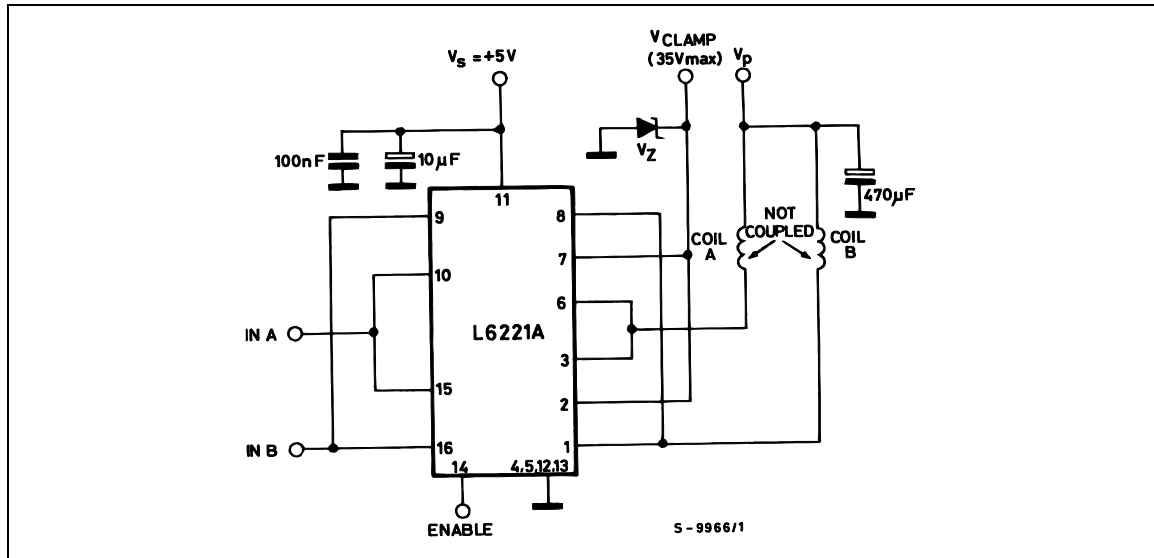


Figure 19 : Driver for Solenoids up to 3A.



Some care must be taken to ensure that the collectors are placed close together to avoid different current partitioning at turn-off.

We suggest to put in parallel channel 1 and 4 and channel 2 and 3 as shown in figure 19 for the similar

electrical characteristics of the logic section (turn-on and turn-off delay time) and the power stages (collector saturation voltage, free-wheeling diode forward voltage).

Figure 20 : Saturation Voltage versus Collector Current

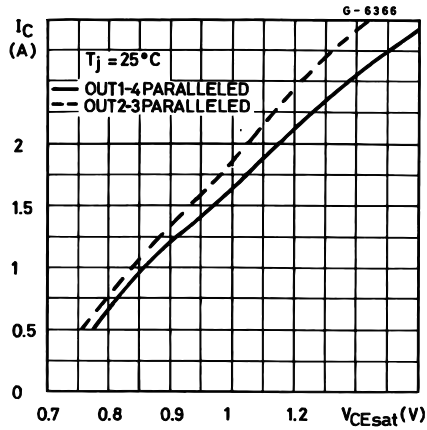


Figure 21 : Peak Collector Current versus Duty Cycle for 1 or 2 Paralleled Outputs Driven (L6221A)

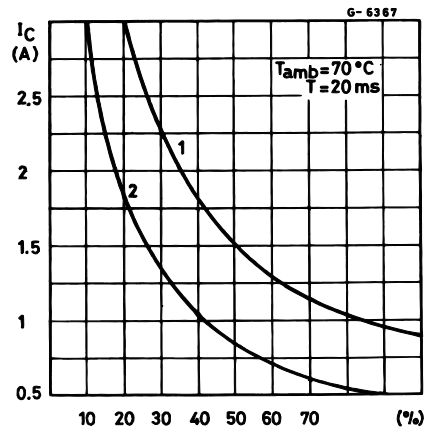
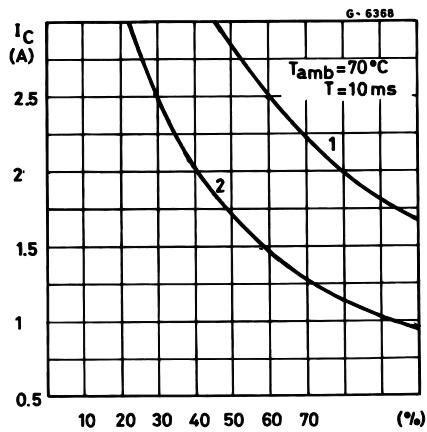


Figure 22 : Peak Collector Current versus Duty Cycle for 1 or 2 Paralleled Outputs Driven (L6221N)



MOUNTING INSTRUCTION

The $R_{th\ j-amb}$ of the L6221A can be reduced by soldering the GND pins to a suitable copper area of the printed circuit board (Fig. 23) or to an external heatsink (Fig. 24).

The diagram of figure 25 shows the maximum dissippable power P_{tot} and the $R_{th\ j-amb}$ as a function of the side "α" of two equal square copper areas hav-

ing a thickness of 35μ (1.4 mils). During soldering the pins temperature must not exceed $260\ ^\circ\text{C}$ and the soldering time must not be longer than 12 seconds.

The external heatsink or printed circuit copper area must be connected to electrical ground.

Figure 23 : Example of P.C. Board Copper Area Which is Used as Heatsink

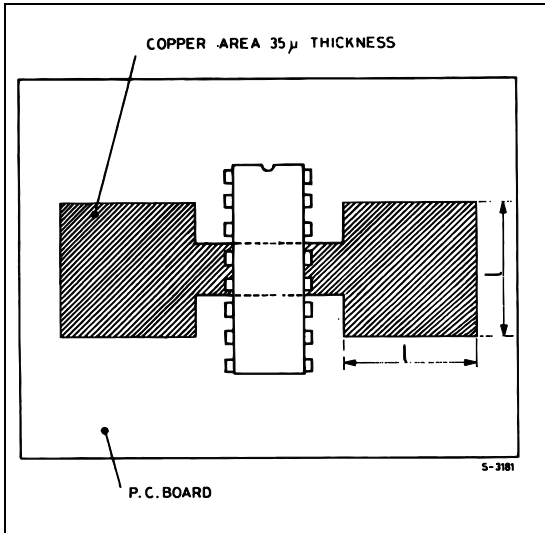


Figure 24 : External Heatsink Mounting Example

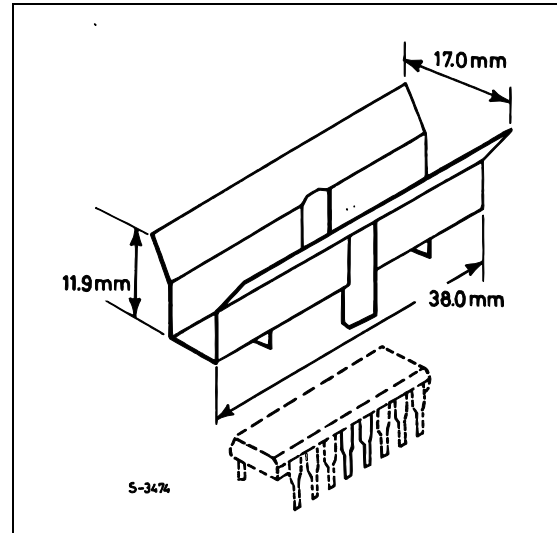


Figure 25 : Maximum Dissippable Power and Junction Thermal Resistance versus Side "α"

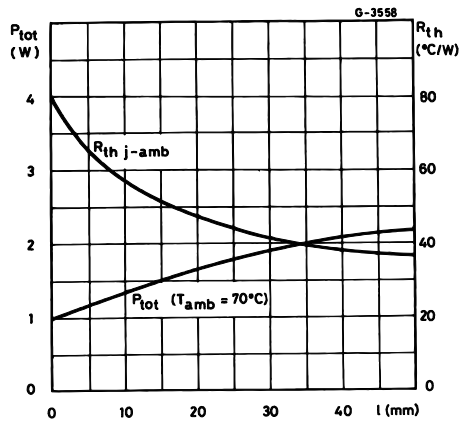
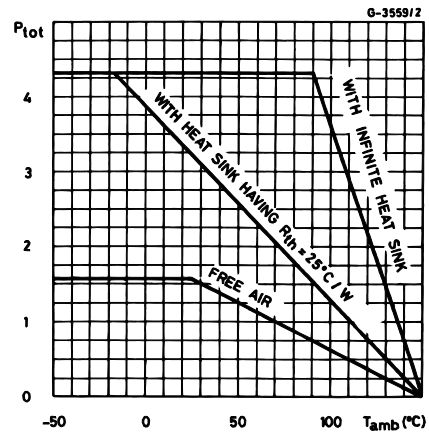


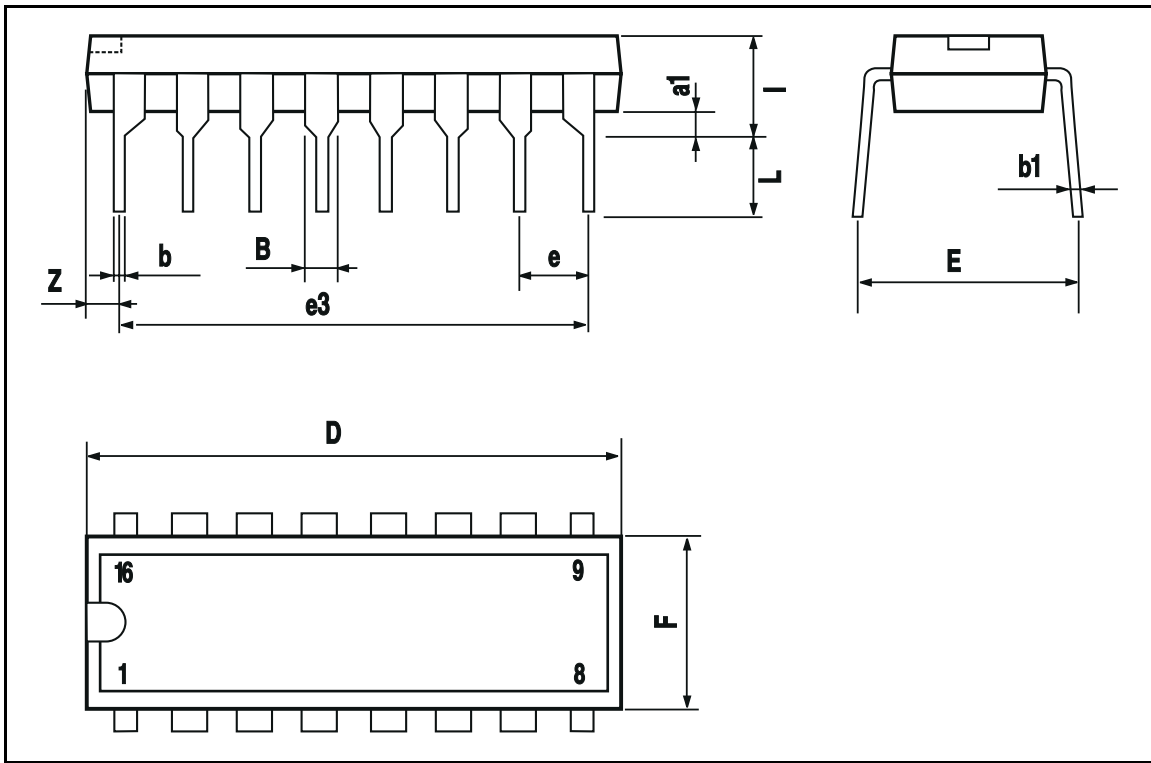
Figure 26 : Maximum Allowable Power Dissipation versus Ambient Temperature



L6221A - L6221AD - L6221N

POWERDIP 16 PACKAGE MECHANICAL DATA

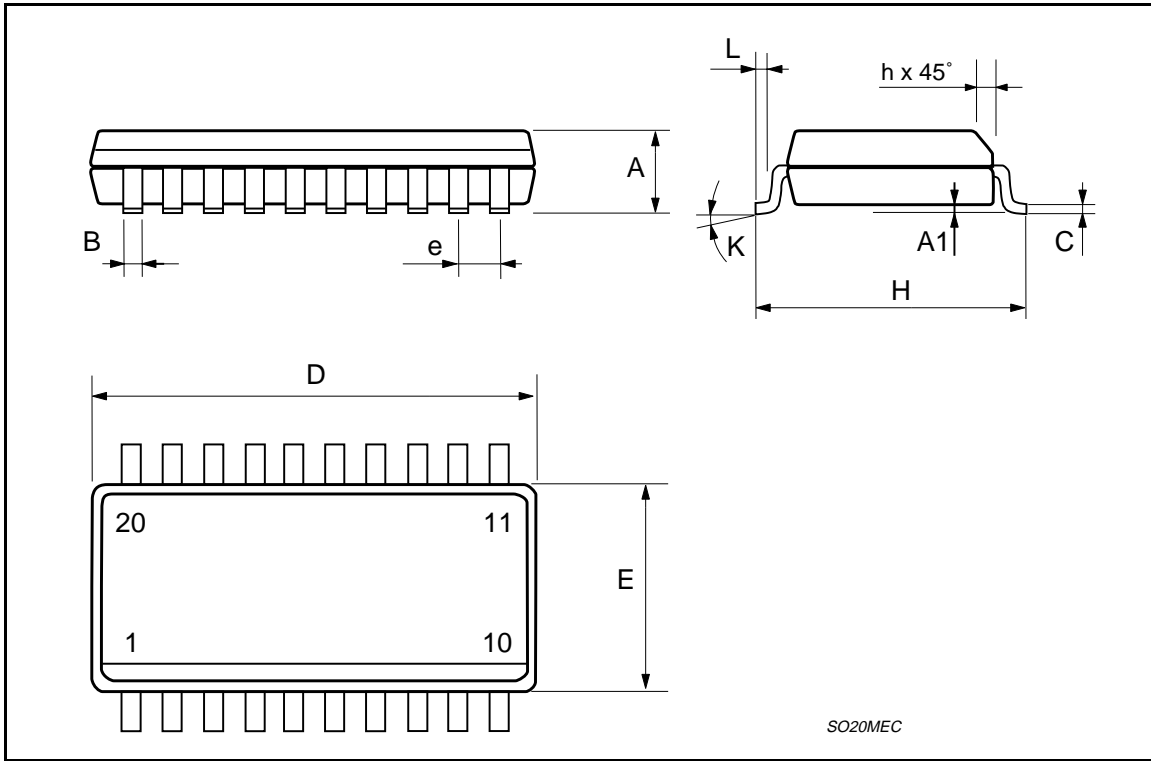
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.85		1.40	0.033		0.055
b		0.50			0.020	
b1	0.38		0.50	0.015		0.020
D			20.0			0.787
E		8.80			0.346	
e		2.54			0.100	
e3		17.78			0.700	
F			7.10			0.280
I			5.10			0.201
L		3.30			0.130	
Z			1.27			0.050



L6221A - L6221AD - L6221N

SO20 PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.35		2.65	0.093		0.104
A1	0.1		0.3	0.004		0.012
B	0.33		0.51	0.013		0.020
C	0.23		0.32	0.009		0.013
D	12.6		13	0.496		0.512
E	7.4		7.6	0.291		0.299
e		1.27			0.050	
H	10		10.65	0.394		0.419
h	0.25		0.75	0.010		0.030
L	0.4		1.27	0.016		0.050
K	0 (min.)8 (max.)					



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